

FE	ATURES	DCC		PACKAGE
٠	Member of Texas Instruments Widebus™	Dee	(TOP VI	
	Family			– í
•	UBT™ Transceiver Combines D-Type Latches	OEAB		56 🛛 CEAB
	and D-Type Flip-Flops for Operation in	LEAB	2	55 CLKAB
	Transparent, Latched, Clocked, or	A1		54 B1
	Clock-Enabled Modes	GND		53 GND
•	OEC [™] Circuitry Improves Signal Integrity and	A2		52 B2
	Reduces Electromagnetic Interference	A3		51 B3
•	Bidirectional Interface Between GTLP Signal	V _{CC} (3.3 V)		50 V _{CC} (5 V)
	Levels and LVTTL Logic Levels	A4		49 B4
•	LVTTL Interfaces are 5-V Tolerant		9	48 B5
•	Medium-Drive GTLP Outputs (34 mA)	A6 GND	10	47 B6 46 GND
•	LVTTL Outputs (–32 mA/64 mA)		12	46 GND 45 B7
	• • • •		13	43 B8
•	GTLP Rise and Fall Times Designed for		14	43 B9
	Optimal Data-Transfer Rate and Signal Integrity in Distributed Loads	A3		42 B10
		A11		41 B11
•	I _{off} Supports Partial-Power-Down Mode	A12		40 B12
	Operation	GND		39 GND
•	Bus Hold on A-Port Inputs	A13	19	38 B13
•	Distributed V _{CC} and GND Pins Minimize	A14	20	37 🛛 B14
	High-Speed Switching Noise	A15	21	36 B15
٠	Latch-Up Performance Exceeds 100 mA Per	V _{CC} (3.3 V)	22	35 🛛 V _{REF}
	JESD 78, Class II	A16		34 🛛 B16
٠	ESD Protection Exceeds JESD 22	A17		33 B17
	– 2000-V Human-Body Model (A114-A)	GND		32 GND
	- 200-V Machine Model (A115-A)	A18		31 B18
	- 1000-V Charged-Device Model (C101)	OEBA		
		LEBA	- 28	29 CEBA
DE	SCRIPTION			

The SN74GTLPH16612 is a medium-drive, 18-bit UBT™ transceiver that provides LVTTL-to-GTLP and GTLP-to-LVTTL signal-level translation. It allows for transparent, latched, clocked, or clock-enabled modes of data transfer. This device provides a high-speed interface between cards operating at LVTTL logic levels and backplanes operating at GTLP signal levels. High-speed (about two times faster than standard LVTTL or TTL) backplane operation is a direct result of the reduced output swing (<1 V), reduced input threshold levels, and OEC[™] circuitry. These improvements minimize bus-settling time and have been designed and tested using several backplane models.

GTLP is a Texas Instruments (TI[™]) derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The ac specification of the SN74GTLPH16612 is given only at the preferred higher noise-margin GTLP, but the user has the flexibility of using this device at either GTL ($V_{TT} = 1.2$ V and $V_{REF} = 0.8$ V) or GTLP ($V_{TT} = 1.5$ V and

 $V_{REF} = 1 V$) signal levels.

The B port normally operates at GTLP levels, while the A-port and control inputs are compatible with LVTTL logic levels and are 5-V tolerant. V_{RFF} is the reference input voltage for the B port.

To improve signal integrity, the SN74GTLPH16612 B-port output transition time is optimized for distributed backplane loads.



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SCESS26C-MARCH 2000-REVISED MAY 2005

DESCRIPTION (CONTINUED)

V_{CC} (5 V) supplies the internal and GTLP circuitry, while V_{CC} (3.3 V) supplies the LVTTL output buffers.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven LVTTL data inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

T _A	PACK	AGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
		Tube	SN74GTLPH16612DL		
–40°C to 85°C	SSOP – DL	Tape and reel	SN74GTLPH16612DLR	GTLPH16612	
	TSSOP – DGG	Tape and reel	SN74GTLPH16612GR	GTLPH16612	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTIONAL DESCRIPTION

The SN74GTLPH16612 is a medium-drive (34 mA), 18-bit UBT transceiver, containing D-type latches and D-type flip-flops to allow data flow in transparent, latched, clocked, and clock-enabled modes and can replace any of the functions shown in Table 1. Data polarity is noninverting.

Table 1. SN74GTLPH16612 UBT Transceiver Replacement Functions

FUNCTION	8 BIT	9 BIT	10 BIT	16 BIT	18 BIT
Transceiver	'245, '623, '645	'863	'861	'16245, '16623	'16863
Buffer/driver	'241, '244, '541		'827	'16241, '16244, '16541	'16825
Latched transceiver	'543			'16543	'16472
Latch	'373, '573	'843	'841	'16373	'16843
Registered transceiver	'646, '652			'16646, '16652	'16474
Flip-flop	'374, '574		'821	'16374	
Standard UBT					'16500, '16501
Universal bus driver					'16835
Registered transceiver with clock enable	'2952			'16470, '16952	
Flip-flop with clock enable	'377	'823			'16823
Standard UBT with clock enable					'16600, '16601

Data flow in each direction is controlled by the clock enables (CEAB and CEBA), latch enables (LEAB and LEBA), clock (CLKAB and CLKBA), and output enables (OEAB and OEBA).

For A-to-B data flow, when CEAB is low, the device operates on the low-to-high transition of CLKAB for the flip-flop and on the high-to-low transition of LEAB for the latch path, i.e., if CEAB and LEAB are low, the A data is latched, regardless of the state of CLKAB (high or low) and if LEAB is high, the device is in transparent mode. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state.

The data flow for B-to-A is similar to that of A-to-B, except that CEBA, OEBA, LEBA, and CLKBA are used.

		INPUTS			OUTPUT	MODE
CEAB	OEAB	LEAB	CLKAB	Α	В	MODE
Х	Н	Х	Х	Х	Z	Isolation
L	L	L	Н	Х	B ₀ ⁽²⁾	Latabad stars as of A data
L	L	L	L	Х	B ₀ ⁽³⁾	Latched storage of A data
Х	L	Н	Х	L	L	True transport
Х	L	Н	Х	Н	н	True transparent
L	L	L	\uparrow	L	L	Clocked storage of A data
L	L	L	\uparrow	н	н	Clocked storage of A data
Н	L	L	Х	Х	B ₀ ⁽³⁾	Clock inhibit

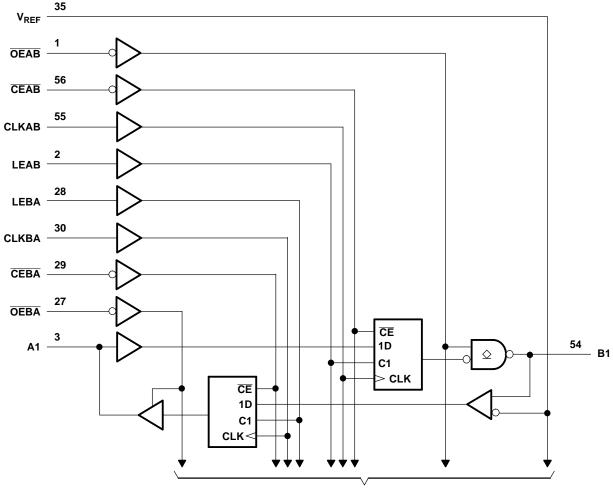
FUNCTION TABLE⁽¹⁾

(1) A-to-B data flow is shown. B-to-A data flow is similar, but uses CEBA, OEBA, LEBA, and CLKBA. The condition when OEAB and OEBA are both low at the same time is not recommended.

(2) Output level before the indicated steady-state input conditions were established, provided that
 (2) Club and CLA and CLA are being to the indicated steady-state input conditions were established, provided that

CLKAB was high before LEAB went low.

(3) Output level before the indicated steady-state input conditions were established.



LOGIC DIAGRAM (POSITIVE LOGIC)

To 17 Other Channels

SN74GTLPH16612 18-BIT LVTTL-TO-GTLP UNIVERSAL BUS TRANSCEIVER

SCES326C-MARCH 2000-REVISED MAY 2005

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V		3.3 V	-0.5	4.6	V
V _{CC}	Supply voltage range	5 V	-0.5	7	v
V	lanut valtaga ranga(2)	A port and control inputs	-0.5	7	V
VI	Input voltage range ⁽²⁾	B port and V _{REF}	-0.5	4.6	v
V	Voltage range applied to any output in the high-impedance or	A port	-0.5	7	V
Vo	power-off state ⁽²⁾	B port	-0.5	4.6	v
	Comment into any output in the law state	A port		128	0
I _O	Current into any output in the low state	B port		80	mA
lo	Current into any A-port output in the high state ⁽³⁾			64	mA
	Continuous current through each V_{CC} or GND			±100	mA
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
0		DGG package		64	°C/W
θ_{JA}	Package thermal impedance ⁽⁴⁾	DL package		56	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. (2)

(3)

This current flows only when the output is in the high state and $V_0 > V_{CC}$. The package thermal impedance is calculated in accordance with JESD 51-7. (4)

Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾

			MIN	NOM	MAX	UNIT
V	Supply voltage	3.3 V	3.15	3.3	3.45	V
V _{CC}	Supply voltage	5 V	4.75	5	5.25	v
V		GTL	1.14	1.2	1.26	V
V_{TT}	Termination voltage	GTLP	1.35	1.5	1.65	v
		GTL	0.74	0.8	0.87	
V _{REF}	Reference voltage	GTLP	0.87	1	1.1	V
V		B port			V _{TT}	
VI	Input voltage	Except B port		V _{CC}	5.5	V
V	High lovel input veltage	B port	V _{REF} + 50 mV			V
V _{IH}	High-level input voltage	Except B port	2			v
V		B port		VR	_{EF} – 50 mV	V
V _{IL}	Low-level input voltage	Except B port			0.8	v
I _{IK}	Input clamp current				-18	mA
I _{OH}	High-level output current	A port			-32	mA
	Level being being being and an and a	A port			64	
I _{OL}	Low-level output current	B port			34	mA
T _A	Operating free-air temperature		-40		85	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Normal connection sequence is GND first, $V_{CC} = 5$ V second, and $V_{CC} = 3.3$ V, I/O, control inputs, V_{TT} , and V_{REF} (any order) last. V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances if the dc recommended I_{OL} ratings are not exceeded.

(3)

(4) V_{REF} can be adjusted to optimize noise margins, but normally is two-thirds V_{TT} .

SCES326C-MARCH 2000-REVISED MAY 2005

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARA	METER		TEST CONDITIONS		MIN TYP ⁽¹⁾ MAX -1.2 -1.2		UNIT	
V _{IK}		V _{CC} (3.3 V) = 3.15 V,	V _{CC} (5 V) = 4.75 V,	l _l = –18 mA			-1.2	V
		V_{CC} (3.3 V) = 3.15 V to 3.45 V_{CC} (5 V) = 4.75 V to 5.25	5 V, V	I _{OH} = -100 μA	V _{CC} (3.3 V) - 0.2			
РАКАІ VIK VOH VOL I	A port			I _{OH} = -8 mA	2.4			V
		$\begin{array}{c c c c c c c c c c c c c c c c c c c $						
				I _{OL} = 100 μA			0.2	
	Amout			I _{OL} = 16 mA			0.4	
V _{OL}	А роп	$V_{\rm CC} (3.3 \text{ V}) = 3.15 \text{ V},$	$V_{\rm CC}$ (5 V) = 4.75 V	I _{OL} = 32 mA			0.5	V
$V_{OH} \qquad A port V_{OL} \qquad A port B port Contra- In A port B port Contra- Inputs A port B port Contra- B port B port Contra- Contra-$								
	B port	V_{CC} (3.3 V) = 3.15 V,	$V_{CC} (5 V) = 4.75 V$ $I_{OH} = I_{OH} = I_{OH} = I_{OH} = I_{OH} = I_{OH} = I_{OL} = V_{CC} (5 V) = 4.75 V, I_{OL} = V_{CC} (5 V) = 0 \text{ or } 5.25 V, V_{I} = 5$ $V_{CC} (5 V) = 5.25 V, V_{I} = 5$ $V_{CC} (5 V) = 5.25 V, V_{I} = 5$ $V_{CC} (5 V) = 5.25 V, V_{I} = 0$ $V_{CC} (5 V) = 5.25 V, V_{O} = I_{VCC} (5 V) = 5.25 V, I_{O} = 0, V_{I} = V_{TT} \text{ or } GND^{(4)}$ $V_{I} = V_{TT} \text{ or } GND^{(4)}$	I _{OL} = 34 mA			0.65	
	Control inputs	V_{CC} (3.3 V) = 0 or 3.45 V,	V_{CC} (5 V) = 0 or 5.25 V,	$= 4.75 \text{ V}, \qquad I_{I} = -18 \text{ mA}$ $I_{OH} = -100 \text{ µA}$ $= 4.75 \text{ V} \qquad I_{OH} = -8 \text{ mA}$ $I_{OH} = -32 \text{ mA}$ $I_{OL} = 100 \text{ µA}$ $I_{OL} = 10 \text{ µA}$ $I_{OL} = 32 \text{ mA}$ $I_{OL} = 32 \text{ mA}$ $I_{OL} = 64 \text{ mA}$ $= 4.75 \text{ V}, \qquad I_{OL} = 34 \text{ mA}$ $= 0 \text{ or } 5.25 \text{ V}, \qquad V_{I} = 5.5 \text{ V}$ $V_{I} = 5.5 \text{ V}$ $V_{I} = 0$ $= 5.25 \text{ V} \qquad V_{I} = 0$ $= 5.25 \text{ V} \qquad V_{I} = 0$ $= 4.75 \text{ V} \qquad V_{I} = 0$ $= 4.75 \text{ V} \qquad V_{I} = 0$ $= 5.25 \text{ V} \qquad V_{I} = 0$ $= 4.75 \text{ V} \qquad V_{I} = 0.8 \text{ V}$ $V_{I} = 0$ $= 4.75 \text{ V} \qquad V_{I} = 0.8 \text{ V}$ $V_{I} = 0 \text{ to } V_{CC} (3.3 \text{ V})$ $V_{I} = 0$ $= 5.25 \text{ V}, \qquad V_{O} = V_{CC} (3.3 \text{ V})$ $= 5.25 \text{ V}, \qquad V_{O} = V_{CC} (3.3 \text{ V})$ $= 5.25 \text{ V}, \qquad V_{O} = 0$ $= 0$			10	
				V _I = 5.5 V			20	
h	A port	V _{CC} (3.3 V) = 3.45 V,	V _{CC} (5 V) = 5.25 V	$V_{I} = V_{CC} (3.3 V)$			1	μA
II II Ioff II(hold)				$V_{I} = 0$			-30	Pr. 1
I _{off}				$V_{I} = V_{CC} (3.3 V)$			5	
	B port	$V_{CC} (3.3 V) = 3.45 V,$	$V_{CC} (5 V) = 5.25 V$	V ₁ = 0	= 0 -		-5	
I _{off}		V _{CC} = 0,	V_{I} or V_{O} = 0 to 4.5 V				100	μA
				V _I = 0.8 V	75			
I _{off}	Anort	V_{aa} (3 3 V) = 3 15 V	V_{aa} (5 V) = 4.75 V	V ₁ = 2 V	-75			μA
'l(hold)	Apon	VCC (0.0 V) = 0.10 V,	VCC (5 V) = 4.75 V				±500	μΑ
	A port	V _{CC} (3.3 V) = 3.45 V,	V _{CC} (5 V) = 5.25 V,	$V_{O} = V_{CC} (3.3 V)$			1	
OZH	B port	V _{CC} (3.3 V) = 3.45 V,	V _{CC} (5 V) = 5.25 V,	V _O = 1.5 V			10	μA
	A port	V_{CC} (3.3 V) = 3.45 V,	V _{CC} (5 V) = 5.25 V,	V _O = 0			-1	
OZL	B port	V_{CC} (3.3 V) = 3.45 V,	V_{CC} (5 V) = 5.25 V,	V _O = 0.65 V			-10	μA
				Outputs high			1	
I_{CC}	A or B	V_{CC} (3.3 V) = 3.45 V, V_{CC} (3.3 V) or $CND^{(3)}$	5 V) = 5.25 V, $I_0 = 0$, V, - V or GND ⁽⁴⁾	Outputs low			5	mA
(0.0 v)	port	$v_{1} = v_{CC} (0.0 v) \text{ or } C(v_{D} v),$		Outputs disabled			1	
				Outputs high			120	
I _{CC} (5.\/)	A or B	V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 V) = 5.25 V, I_{O} = 0,		Outputs low		120		mA
(0 V)	port			Outputs disabled			120	
ΔI _{CC} (3.3 V) ⁽⁵⁾		V_{CC} (3.3 V) = 3.45 V, V_{CC} (5 V) = 5.25 V, One A-port or control input at 2.7 V, Other A-port or control inputs at V_{CC} (3.3 V) or GND					1	mA
C _i	Control inputs	V _I = 3.15 V or 0				4		pF
<u> </u>	A port	V _O = 3.15 V or 0				8.5		
C _{io}	B port	V _O = 1.5 V or 0				8		pF

(1)

All typical values are at V_{CC} (3.3 V) = 3.3 V, V_{CC} (5 V) = 5 V, $T_A = 25^{\circ}C$. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to (2) another.

This is the V_I for A-port or control inputs. This is the V_I for B port. (3)

(4)

(5) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

SN74GTLPH16612 18-BIT LVTTL-TO-GTLP UNIVERSAL BUS TRANSCEIVER

SCES326C-MARCH 2000-REVISED MAY 2005

Timing Requirements

over recommended ranges of supply voltage and operating free-air temperature,

 V_{TT} = 1.5 V and V_{REF} = 1 V for GTLP (unless otherwise noted) (see Figure 1)

			MIN	MAX	UNIT
f _{clock}	Clock frequency			85	MHz
	Dulas duration	LEAB or LEBA high	3.3		20
t _w	Pulse duration	CLKAB or CLKBA high or low	5.7		ns
	k Clock frequency Pulse duration Setup time Hold time	A before CLKAB1	1		
		B before CLKBA↑	1.8		
t _{ev}	O a torra d'ana	A before LEAB↓	0.5		
τ _{su}	Setup time	B before LEBA↓	1.2		ns
		CEAB before CLKAB↑	AB before CLKAB↑ 1.2		
		CEBA before CLKBA↑	1.4		
	Pulse duration Setup time	A after CLKAB↑	1.9		
		B after CLKBA↑	0.5		
		A after LEAB↓	2.7		
ι _h	Hold time	B after LEBA↓	3.5		ns
		CEAB after CLKAB↑	1.2		
		CEBA after CLKBA↑	1.1		

TEXAS

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Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,

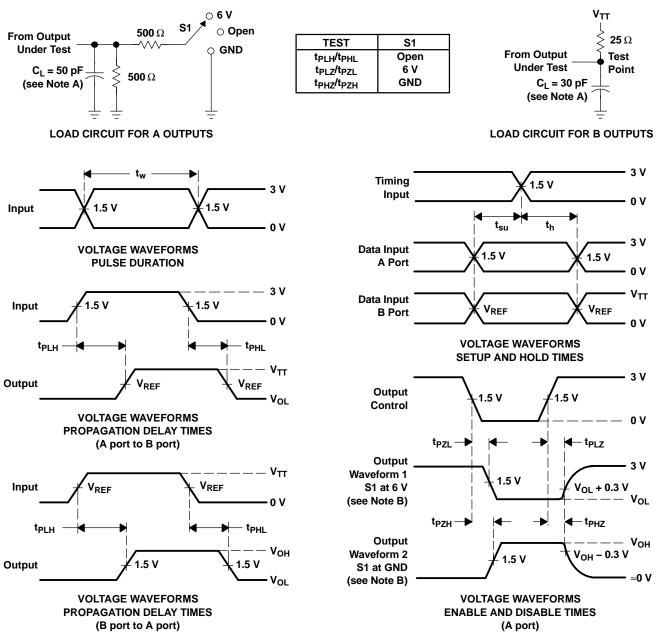
 $V_{TT} = 1.5 \text{ V} \text{ and } V_{REF} = 1 \text{ V} \text{ for GTLP} \text{ (see Figure 1)}$

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN TYP ⁽¹⁾	МАХ	UNIT
f _{max}			85		MHz
t _{PLH}	- A	В	2.5	6.9	ns
t _{PHL}	A	D	2.5	6.9	115
t _{PLH}	LEAB	В	3.2	7.3	ns
t _{PHL}	LEAD	D	3.2	7.3	115
t _{PLH}	CLKAB	В	3.4	7.8	20
t _{PHL}	CLRAB	D	3.4	7.8	ns
t _{en}	OEAB	В	2.8	7	20
t _{dis}	UEAB	D	2.8	7	ns
t _r	Transition time, B o	2.6		ns	
t _f	Transition time, B o	utputs (80% to 20%)	2.6		ns
t _{PLH}	P	٨	1.5	5.7	~~~
t _{PHL}	В	A	1.5	5.7	ns
t _{PLH}	LEBA	٨	1.8	5.7	~~~
t _{PHL}	LEDA	A	1.8	5.7	ns
t _{PLH}		٨	2.3	5.5	20
t _{PHL}	CLKBA	A	2.3	5.5	ns
t _{en}	OEBA	۸	1.8	6.1	20
t _{dis}	UEDA	A	1.8	6.1	ns

(1) All typical values are at V_{CC} (3.3 V) = 3.3 V, V_{CC} (5 V) = 5 V, T_A = 25°C.

SCES326C-MARCH 2000-REVISED MAY 2005

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

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- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_r \leq 2.5 ns. t_f \leq 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

SN74GTLPH16612 18-BIT LVTTL-TO-GTLP UNIVERSAL BUS TRANSCEIVER

SCES326C-MARCH 2000-REVISED MAY 2005

Distributed-Load Backplane Switching Characteristics

The previous switching characteristics table shows the switching characteristics of the device into a lumped load (Figure 1). However, the designer's backplane application probably is a distributed load. The physical representation is shown in Figure 2. This backplane, or distributed load, can be approximated closely to an RLC circuit, as shown in Figure 3. This device has been designed for optimum performance in this RLC circuit. The following switching characteristics table shows the switching characteristics of the device into the RLC load, to help the designer better understand the performance of the GTLP device in this typical backplane. See www.ti.com/sc/gtlp for more information.

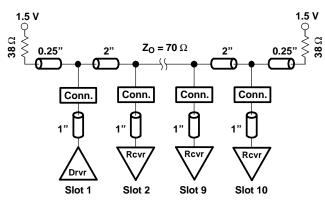
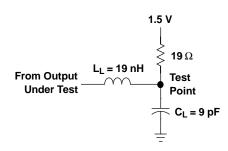


Figure 2. Medium-Drive Test Backplane



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Figure 3. Medium-Drive RLC Network

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5$ V and $V_{REF} = 1$ V for GTLP (see Figure 3)

PARAMETER	FROM (INPUT)	MIN TYP ⁽¹⁾	UNIT		
f _{max}			85	MHz	
t _{PLH}	^	В	3.6	20	
t _{PHL}	— A	В	3.6	ns	
t _{PLH}	LEAB	В	4.3	ns	
t _{PHL}	LLAD	В	4.3		
t _{PLH}	CLKAB	В	4.4		
t _{PHL}	CERAB	В	4.4	ns	
t _{en}	OEAB	В	4.1		
t _{dis}	OEAB	В	4.3	ns	
t _r	Rise time, B outp	1.4	ns		
t _f	Fall time, B outpu	2.1	ns		

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C. All values are derived from TI SPICE models.



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
74GTLPH16612DLG4	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
74GTLPH16612DLRG4	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
74GTLPH16612GRE4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
74GTLPH16612GRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
SN74GTLPH16612DL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
SN74GTLPH16612DLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples
SN74GTLPH16612GR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH16612	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



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11-Apr-2013

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74GTLPH16612DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
SN74GTLPH16612GR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74GTLPH16612DLR	SSOP	DL	56	1000	367.0	367.0	55.0
SN74GTLPH16612GR	TSSOP	DGG	56	2000	367.0	367.0	45.0

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice. В.
 - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
 - D. Falls within JEDEC MO-118

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MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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